TOSHIBA Photocoupler GaAs Ired & Photo-Thyristor

TLP541G,TLP542G

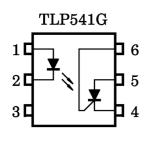
Programmable Controllers
AC-Output Module
Solid State Relay

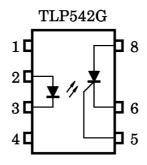
The TOSHIBA TLP541G consists of a photo-thyristor optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

The TOSHIBA TLP542G consists of a photo–thyristor optically coupled to a gallium arsenide infrared emitting diode in a seven lead plastic DIP package.

- Peak off-state voltage: 400 V (min.)
- Trigger LED current: 7 mA (max.)
- On-state current: 150 mA (max.)
- Isolation voltage: 2500 V_{rms} (min.)
- UL recognized: UL1577, file no. E67349

Pin Configuration (top view)

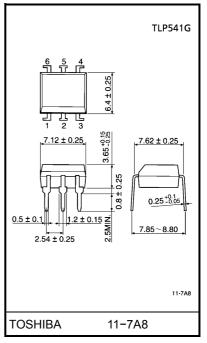




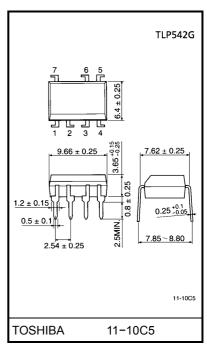
- 1: ANODE
- 2: CATHODE
- 3 : N.C.
- 4: CATHODE
- 5: ANODE
- **6** : **GATE**

- 1: N.C.
- 2: ANODE
- 3: CATHODE
- 4 : N.C.
- 5: GATE
- 6: CATHODE
- 7: ANODE

Unit in mm



Weight: 0.4 g



Weight: 0.53 g



Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
	Forward current	Ι _F	70	mA	
	Forward current derating (Ta ≥ 25°C)	ΔI _F / °C	-0.7	mA / °C	
LED	Peak forward current (100 µs pulse, 100 pps)	I _{FP}	1	Α	
	Reverse voltage	V _R	5	V	
	Junction temperature	Tj	125	°C	
	Peak forward voltage ($R_{GK} = 27k\Omega$)	V_{DRM}	400	V	
or	Peak reverse voltage ($R_{GK} = 27k\Omega$)	V_{RRM}	400	V	
	On–state current	I _{T (RMS)}	150	mA	
Detector	On–state current derating (Ta ≥ 25°C)	ΔI _T / °C	-2.0	mA / °C	
ă	Peak one cycle surge current	I _{TSM}	2	Α	
	Peak reverse gate voltage	V_{GM}	-5	V	
	Junction temperature	Tj	100	°C	
Storag	Storage temperature range		-55~125	°C	
Operating temperature range		T _{opr}	-30~100	°C	
Lead soldering temperature (10 s)		T _{sol}	260	°C	
Isolatio	Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note)		2500	V _{rms}	

(Note) Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V_{AC}	_	_	120	V _{ac}
Forward current	I _F	10	16	25	mA
Operating temperature	T _{opr}	-30	_	85	°C
Gate to cathode resistance	R _{GK}	_	27	33	kΩ
Gate to cathode capacity	C _{GK}	-	0.01	0.1	μF



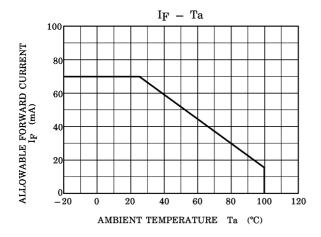
Individual Electrical Characteristics (Ta = 25°C)

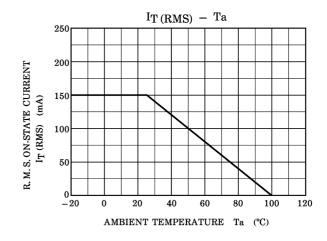
Characteristic		Symbol	Test Condition		Min.	Тур.	Max.	Unit
LED	Forward voltage	V _F	I _F = 10 mA		1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V		_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz		_	30	_	pF
Detector	Off-state current	I _{DRM}	VAK - 400 V	Ta = 25°C	_	10	5000	nA
				Ta = 100°C	_	1	100	μΑ
	Reverse current	I _{RRM}	V _{KA} = 400 V	Ta = 25°C	_	10	5000	nA
			R_{GK} = 27 k Ω	Ta = 100°C	_	1	100	μΑ
	On-state voltage	V _{TM}	I _{TM} = 100 mA		_	0.9	1.3	V
	Holding current	lΗ	R _{GK} = 27 kΩ		_	0.2	1	mA
	Off–state dv/dt	dv/dt	$V_{AK} = 280 \text{ V}, R_{GK} = 27 \text{ k}\Omega$		5	10	_	V/µs
	Capacitance C _j		V = 0, f = 1 MHz A	node to gate	_	20	_	, F
		G	ate to cathode	_	350	_	pF	

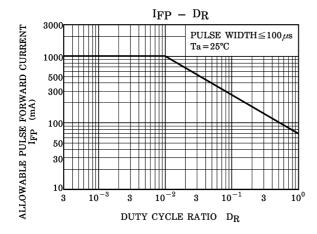
Coupled Characteristics (Ta = 25°C)

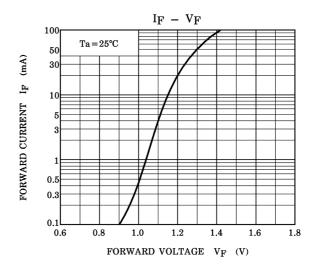
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	V_{AK} = 6 V, R_{GK} = 27 k Ω	1	4	7	mA
Turn-on time	t _{on}	I_F = 50 mA, R_{GK} = 27 kΩ	_	10	_	μs
Capacitance (input to output)	CS	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	_	10 ¹¹	_	Ω
Isolation voltage	BVS	AC, 1 minute	2500	_	_	V _{rms}

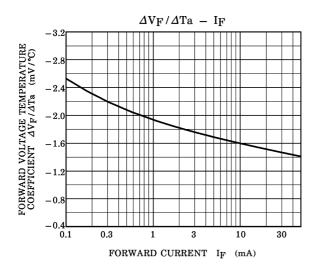
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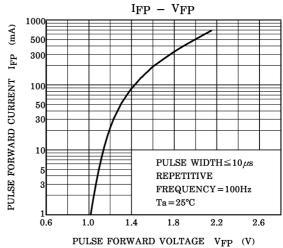


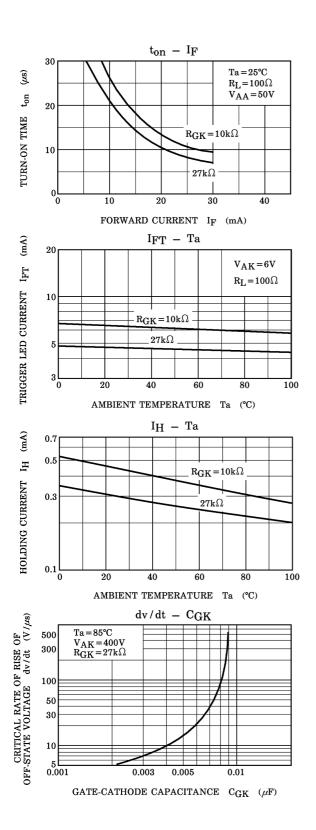


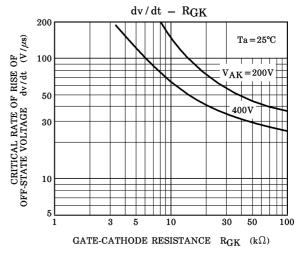


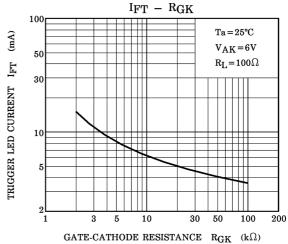


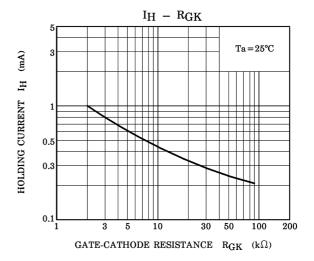












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